NSN 5961-01-344-4966

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-344-4966 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.107 inches **Function For Which Designed:** Switching **End Application:** Strategic weapon systems (poseidon and trident) Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 reverse voltage, peak **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute **Capacitance Rating In Picofarads:** 2.0 **Special Features:** Weapon system essential; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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